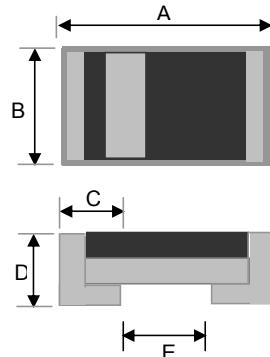


### Small Signal Diode


**0805**


### Features

- ◊ Designed for mounting on small surface.
- ◊ Extremely thin/leadless package
- ◊ High mounting capability, strong surge with stand, high reliability.
- ◊ Pb free version and RoHS compliant
- ◊ Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

### Mechanical Data

- ◊ Case :0805 standard package, molded plastic
- ◊ Terminal: Gold plated, solderable per MIL-STD-750, method 2026 guaranteed
- ◊ High temperature soldering guaranteed: 260°C/10s
- ◊ Polarity : Indicated by cathode band
- ◊ Weight : 0.006 gram (approximately)

Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.80	2.20	0.071	0.086
B	1.05	1.45	0.410	0.570
C	0.25	0.65	0.010	0.026
D	0.75	0.95	0.029	0.037
E	1.30	0.90	0.051	0.034

### Ordering Information

Part No.	Package	Packing
TS4148 RY	0805	5Kpcs / 7" Reel

### Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

#### Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P <sub>D</sub>	400	mW
Non-Repetitive Peak Reverse Voltage	V <sub>RSM</sub>	100	V
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	75	V
Repetitive Peak Forward Current	I <sub>FRM</sub>	300	mA
Mean Forward Current	I <sub>o</sub>	150	mA
Non-Repetitive Peak Forward Surge Current Tp=1sec square waveform 8.3ms single half sine waveform	I <sub>FSM</sub>	0.5 2.0	A
Thermal Resistance (Junction to Ambient) (Note 1)	R <sub>θJA</sub>	375	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to + 175	°C

#### Electrical Characteristics

Type Number	Symbol	Min	Max	Units
Reverse Breakdown Voltage (Note 2)	V <sub>(BR)</sub>	-	75	V
Forward Voltage I <sub>F</sub> = 10mA	V <sub>F</sub>	-	1.00	V
Reverse Leakage Current V <sub>R</sub> = 20V V <sub>R</sub> = 75V	I <sub>R</sub>	-	25	nA
		-	5	μA
Junction Capacitance V <sub>R</sub> =0, f=1.0MHz	C <sub>J</sub>		4.0	pF
Reverse Recovery Time (Note3)	Tr		4	ns

Notes:1. Valid provided that electrodes are kept at ambient temperature

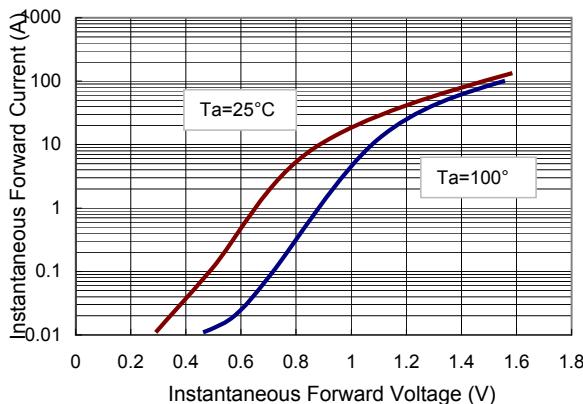
Notes:2. Test Condition : I<sub>R</sub>=100μA

Notes:3. Test Condition : I<sub>F</sub>=10mA, I<sub>R</sub>=1mA, R<sub>L</sub>=100Ω

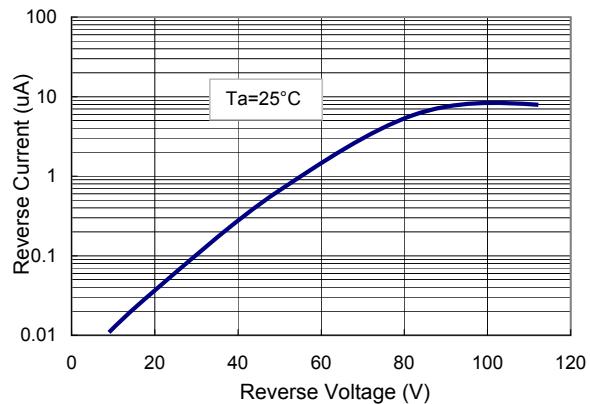
## Small Signal Diode

### Rating and Shacteristic Curves

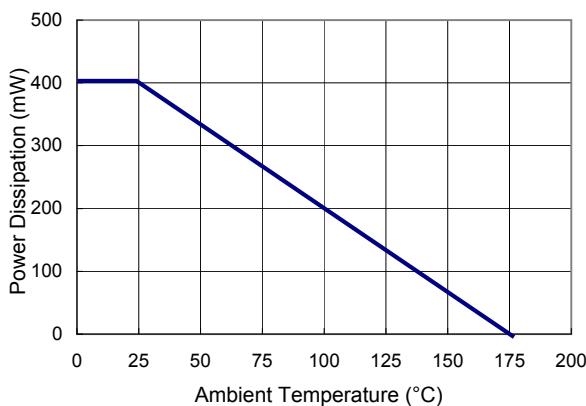
**FIG 1 Typical Forward Characteristics**



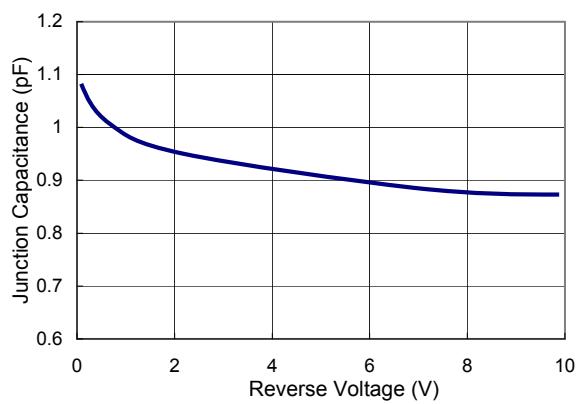
**FIG 2 Reverse Current vs Reverse Voltage**



**FIG 3 Admissible Power Dissipation Curve**



**FIG 4 Typical Junction Capacitance**



**FIG 5 Forward Resistance vs. Forward Current**

